

## 1N746 thru 1N759A, -1 and 1N4370 thru 1N4372A, -1 DO-35

Silicon 500 mW Zener Diodes



#### **DESCRIPTION**

The popular 1N746 thru 1N759A and 1N4370 thru 1N4372A series of 0.5 watt Zener Voltage Regulators provides a selection from 2.4 to 12 volts in standard 5% or 10% tolerances as well as tighter tolerances identified by different suffix letters on the part number. These glass axial-leaded DO-35 Zeners are also available with an internal-metallurgical-bond option by adding a "-1" suffix. These are also available in JAN, JANTX, and JANTXV military qualifications. Microsemi also offers numerous other Zener products to meet higher and lower power applications.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

# DO-35 (DO-204AH)

#### **FEATURES**

- JEDEC registered 1N746 thru 1N759A and 1N4370 thru 1N4372A series
- Internal metallurgical bond option available by adding a "-1" suffix
- Also available in JAN, JANTX, and JANTXV qualifications per MIL-PRF-19500/127 by adding the JAN, JANTX, or JANTXV prefixes to part numbers for desired level of screening as well as -1" suffix; (e.g. JANTX1N751A-1, JANTXV1N758C-1, etc.)
- Military Surface Mount equivalents also available in DO-213AA by adding a UR-1 suffix in addition to the JAN, JANTX, and JANTXV prefix; e.g. JANTX1N962BUR-1 (see separate data sheet)
- Commercial Surface Mount equivalents available as MLL746 to MLL759A and MLL4370 to MLL4372A including the "-1" suffix in the DO-213AA MELF style package (consult factory for others)
- DO-7 glass body axial-leaded Zener equivalents are also available

#### **APPLICATIONS / BENEFITS**

- Regulates voltage over a broad operating current and temperature range
- Selection from 2.4 to 12 V
- Standard voltage tolerances are plus/minus 5% with A suffix identification and 10 % with no suffix
- Tight tolerances available in plus or minus 2% or 1% with C or D suffix respectively
- Flexible axial-lead mounting terminals
- Nonsensitive to ESD per MIL-STD-750 Method 1020
- Minimal capacitance (see Figure 3)
- Inherently radiation hard as described in Microsemi MicroNote 050

### **MAXIMUM RATINGS**

- Operating and Storage temperature: -65°C to +175°C
- Thermal Resistance: 250 °C/W junction to lead at 3/8 (10 mm) lead length from body, or 310 °C/W junction to ambient when mounted on FR4 PC board (1 oz Cu) with 4 mm² copper pads and track width 1 mm, length 25 mm
- Steady-State Power: 0.5 watts at T<sub>L</sub> ≤ 50°C 3/8 inch (10 mm) from body or 0.48 W at T<sub>A</sub> ≤ 25°C when mounted on FR4 PC board as described for thermal resistance above (also see Figure1)
- Forward voltage @200 mA: 1.1 volts
- Solder Temperatures: 260 °C for 10 s (max)

### **MECHANICAL AND PACKAGING**

- CASE: Hermetically sealed axial-lead glass DO-35 (DO-204AH) package
- TERMINALS: Leads, tin-lead plated solderable per MIL-STD-750, method 2026
- POLARITY: Cathode indicated by band. Diode to be operated with the banded end positive with respect to the opposite end for Zener regulation
- MARKING: Part number
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- WEIGHT: 0.2 grams
- See package dimensions on last page

+.062



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#### **ELECTRICAL CHARACTERISTICS\* @ 25°C** NOMINAL ZENER MAXIMUM **MAXIMUM REVERSE** MAXIMUM **TYPICAL** TEMP COEFF. **JEDEC ZENER TEST ZENER CURRENT IR ZENER VOLTAGE CURRENT IMPEDANCE** @ V<sub>R</sub> = 1 VOLT **CURRENT OF ZENER** TYPE NO. **VOLTAGE** $V_z @ I_{zt}$ $I_{ZT}$ Z<sub>ZT</sub> @ I<sub>ZT</sub> $I_{ZM}$ (NOTE1) (NOTE 2) (NOTE 3) @25°C @+150°C (NOTE 4) αν7 %/°C **VOLTS** mA **OHMS** mΑ μΑ μΑ 1N4370 24 20 30 100 200 150 - 085 2.7 -.080 1N4371 30 20 75 150 135 1N4372 3.0 20 29 50 100 120 -.075 1N746 28 3.3 20 10 30 110 -.066 1N747 -.058 3.6 20 24 10 30 100 1N748 20 23 10 30 95 -.046 3.9 1N749 4.3 20 22 2 30 85 -.033 1N750 4.7 20 19 2 30 75 -.015 1N751 5.1 20 17 1 20 70 +/-.010 1N752 +.030 5.6 20 11 20 65 1N753 20 20 6.2 .1 60 +.049 1N754 20 5 20 55 +.053 6.8 .1 1N755 6 20 50 7.5 20 .1 +.0571N756 8.2 20 8 20 45 +.060 1N757 9.1 20 10 20 40 +.061 1 1N758 10.0 20 20 17 .1 35 +.062

#### \* JEDEC Registered Data

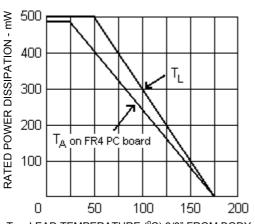
12.0

1N759

- NOTE 1: Standard tolerance on JEDEC types shown is +/- 10%. Suffix letter A denotes +/- 5% tolerance; suffix letter C denotes +/- 2%; and suffix letter D denotes +/- 1% tolerance.
- NOTE 2: Voltage measurements to be performed 20 seconds after application of dc test current.
- NOTE 3: Zener impedance derived by superimposing on I<sub>ZT</sub>, a 60 cps, rms ac current equal to 10% I<sub>ZT</sub> (2mA ac). See MicroNote 202 for typical zener Impedance variation with different operating currents.
- **NOTE 4:** Allowance has been made for the increase in  $V_Z$  due to  $Z_Z$  and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

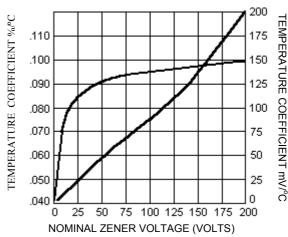
## GRAPHS

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 $T_L$  – LEAD TEMPERATURE (°C) 3/8" FROM BODY or  $T_A$  on FR4 PC BOARD FIGURE 1

POWER DERATING CURVE



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FIGURE 2
ZENER VOLTAGE TEMPERATURE
COEFFICIENT vs. ZENER VOLTAGE

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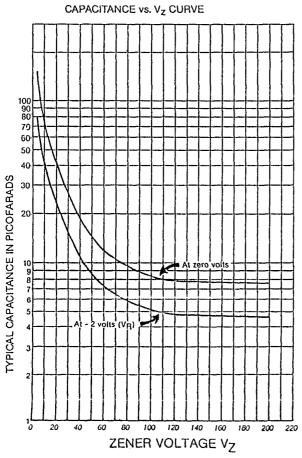


FIGURE 3
CAPACITANCE vs. ZENER VOLTAGE
(TYPICAL)

